PRODUCT NAME : CD4046 Micropower Phase-locked Loop

PRICE : Rs 29.00
SKU : RM0701

DESCRIPTION

Features

- Consisting of a Linear, Voltage-Controlled Oscillator and two Phase Comparators
- The VCO Produces an Output Signal Whose Frequency is Determined by the Input Voltage
- Inhibit Control Pin
- Operating Temperature to 85oC
- Low Power TTL

FAIRCHILD SEMICONDUCTOR™

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CD4046BC
Micropower Phase-Locked Loop

General Description

The CD4046BC micropower phase-locked loop (PLL) consists of a low power, linear, voltage-controlled oscillator (VCO), a source follower, a zener diode, and two phase comparators. The two phase comparators have a common signal input and a common comparator input. The signal input can be directly coupled for a large voltage signal, or capacitively coupled to the self-biasing amplifier at the signal input for a small voltage signal.

Phase comparator I, an exclusive OR gate, provides a digital error signal (phase comp. I Out) and maintains 90° phase shifts at the VCO center frequency. Between signal input and comparator input (both at 50% duty cycle), it may lock onto the signal input frequencies that are close to harmonics of the VCO center frequency.

Phase comparator II is an edge-controlled digital memory network. It provides a digital error signal (phase comp. II Out) and lock-in signal (phase pulses) to indicate a locked condition and maintains a 0° phase shift between signal input and comparator input.

The linear voltage-controlled oscillator (VCO) produces an output signal (VCO Out) whose frequency is determined by the voltage at the VCO_{IN} input, and the capacitor and resistors connected to pin $C1_A$, $C1_B$, R1 and R2.

The source follower output of the VCO_{IN} (demodulator Out) is used with an external resistor of 10 kΩ or more.

The INHIBIT input, when high, disables the VCO and source follower to minimize standby power consumption. The zener diode is provided for power supply regulation, if necessary.

Features

- Wide supply voltage range: 3.0V to 18V
- Low dynamic power consumption: 70 µW (typ.) at f_o = 10 kHz, V_{DD} = 5V
- VCO frequency: 1.3 MHz (typ.) at V_{DD} = 10V
- Low frequency drift: 0.06%/°C at V_{DD} = 10V with temperature
- High VCO linearity: 1% (typ.)

Applications

- FM demodulator and modulator
- Frequency synthesis and multiplication
- Frequency discrimination
- Data synchronization and conditioning
- Voltage-to-frequency conversion
- Tone decoding
- FSK modulation
- Motor speed control

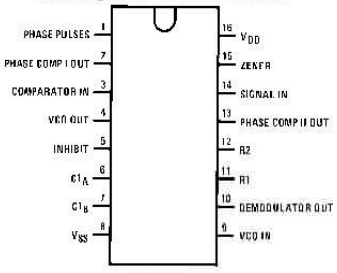
Ordering Code:

Order Number	Package Number	Package Description
CD4046BCM	M16A	16-Lead Small Outline integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Body
CD4046BCN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignments for SOIC and DIP



Top View

Absolute Maximum Ratings (Note 1)

(Note 2)

DC Supply Voltage (V_{DD})	−0.5 to +18 V_{DC}
Input Voltage (V_{IN})	−0.5 to V_{DD} +0.5 V_{DC}
Storage Temperature Range (T_S)	−65°C to +150°C
Power Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V_{DD})	3 to 15 V_{DC}
Input Voltage (V_{IN})	0 to V_{DD} V_{DC}
Operating Temperature Range (T_A)	−40°C to +85°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Note 2: V_{SS} = 0V unless otherwise specified.

DC Electrical Characteristics (Note 2)

Symbol	Parameter	Conditions	−40°C		+25°C			+85°C		Units
			Min	Max	Min	Typ	Max	Min	Max	
I_{DD}	Quiescent Device Current	Pin 5 = V_{DD}, Pin 14 = V_{DD}, Pin 3, 9 = V_{SS}								
		V_{DD} = 5V		20		0.005	20		150	µA
		V_{DD} = 10V		40		0.01	40		300	µA
		V_{DD} = 15V		80		0.015	80		600	µA
		Pin 5 = V_{DD}, Pin 14 = Open, Pin 3, 9 = V_{SS}								
		V_{DD} = 5V		70		5	55		205	µA
		V_{DD} = 10V		530		20	410		710	µA
		V_{DD} = 15V		1500		50	1200		1800	µA
V_{OL}	LOW Level Output Voltage	V_{DD} = 5V		0.05		0	0.05		0.05	V
		V_{DD} = 10V		0.05		0	0.05		0.05	V
		V_{DD} = 15V		0.05		0	0.05		0.05	V
V_{OH}	HIGH Level Output Voltage	V_{DD} = 5V	4.95		4.95	5		4.95		V
		V_{DD} = 10V	9.95		9.95	10		9.95		V
		V_{DD} = 15V	14.95		14.95	15		14.95		V
V_{IL}	LOW Level Input Voltage	V_{DD} = 5V, V_O = 0.5V or 4.5V		1.5		2.25	1.5		1.5	V
	Comparator and Signal In	V_{DD} = 10V, V_O = 1V or 9V		3.0		4.5	3.0		3.0	V
		V_{DD} = 15V, V_O = 1.5V or 13.5V		4.0		6.25	4.0		4.0	V
V_{IH}	HIGH Level Input Voltage	V_{DD} = 5V, V_O = 0.5V or 4.5V	3.5		3.5	2.75		3.5		V
	Comparator and Signal In	V_{DD} = 10V, V_O = 1V or 9V	7.0		7.0	5.5		7.0		V
		V_{DD} = 15V, V_O = 1.5V or 13.5V	11.0		11.0	8.25		11.0		V
I_{OL}	LOW Level Output Current	V_{DD} = 5V, V_O = 0.4V	0.52		0.44	0.88		0.36		mA
	(Note 4)	V_{DD} = 10V, V_O = 0.5V	1.3		1.1	2.25		0.9		mA
		V_{DD} = 15V, V_O = 1.5V	3.6		3.0	8.8		2.4		mA
I_{OH}	HIGH Level Output Current	V_{DD} = 5V, V_O = 4.6V	−0.52		−0.44	−0.88		−0.36		mA
	(Note 4)	V_{DD} = 10V, V_O = 9.5V	−1.3		−1.1	−2.25		−0.9		mA
		V_{DD} = 15V, V_O = 13.5V	−3.6		−3.0	−8.8		−2.4		mA
I_{IN}	Input Current	All Inputs Except Signal Input								
		V_{DD} = 15V, V_{IN} = 0V		−0.3		-10^{-5}	−0.3		−1.0	µA
		V_{DD} = 15V, V_{IN} = 15V		0.3		10^{-5}	0.3		1.0	µA
C_{IN}	Input Capacitance	Any Input (Note 3)					7.5			pF
P_T	Total Power Dissipation	f_o = 10 kHz, R1 = 1 MΩ, R2 = ∞, $\varsigma XO_{IN} = \varsigma_{\Delta\Delta}/2$								
		V_{DD} = 5V				0.07				mW
		V_{DD} = 10V				0.6				mW
		V_{DD} = 15V				2.4				mW

Note 3: Capacitance is guaranteed by periodic testing.

Note 4: I_{OH} and I_{OL} are tested one output at a time.